# **NTSX2102**

# Dual supply translating transceiver; open drain; auto direction sensing

Rev. 2 — 11 February 2013

**Product data sheet** 

# 1. General description

The NTSX2102 is a 2-bit, dual supply translating transceiver with auto direction sensing, that enables bidirectional voltage level translation. It features two 2-bit input-output ports (An and Bn), one output enable input (OE) and two supply pins ( $V_{CC(A)}$  and  $V_{CC(B)}$ ). Both supplies can be supplied at any voltage between 1.65 V and 5.5 V. This flexibility makes the device suitable for translating between any of the voltage nodes (1.8 V, 2.5 V, 3.3 V and 5.0 V). Pins An and OE are referenced to  $V_{CC(A)}$  and pins Bn are referenced to  $V_{CC(B)}$ . A LOW level at pin OE causes the outputs to assume a high-impedance OFF-state. This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

## 2. Features and benefits

- Wide supply voltage range:
  - ◆ V<sub>CC(A)</sub>: 1.65 V to 5.5 V and V<sub>CC(B)</sub>: 1.65 V to 5.5 V
- Maximum data rates:
  - ♦ 50 Mbps
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Inputs accept voltages up to 5.5 V
- ESD protection:
  - ♦ HBM JS-001 Class 2 exceeds 2000 V
  - CDM JESD22-C101E exceeds 2000 V
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Multiple package options
- Specified from -40 °C to +85 °C

# 3. Applications

- I<sup>2</sup>C/SMBus
- UART
- GPIO



## Dual supply translating transceiver; open drain; auto direction sensing

# 4. Ordering information

Table 1. Ordering information

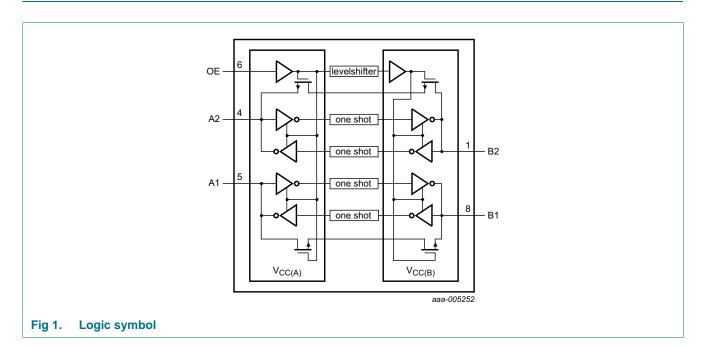
Type number	Package	Package							
	Temperature range	Name	Description	Version					
NTSX2102GM	–40 °C to +85 °C	XQFN8	plastic extremely thin quad flat package; no leads; 8 terminals; body 1.6 $\times$ 1.6 $\times$ 0.5 mm	SOT902-2					
NTSX2102GU8	–40 °C to +85 °C	XQFN8	XQFN8: plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.4 $\times$ 1.2 $\times$ 0.5 mm	SOT1309-1					
NTSX2102GD	–40 °C to +85 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body $3 \times 2 \times 0.5$ mm	SOT996-2					

# 5. Marking

#### Table 2. Marking

Type number	Marking code
NTSX2102GM	sX2
NTSX2102GU8	sX
NTSX2102GD	sX2

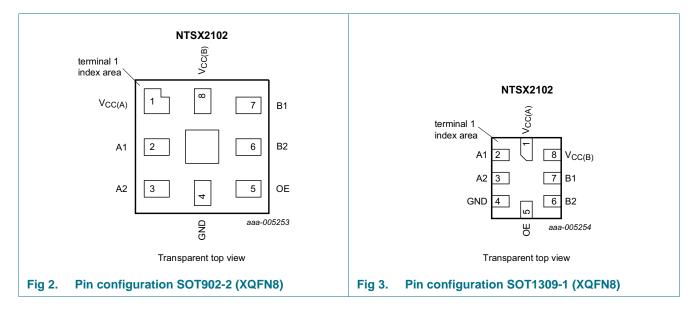
# 6. Functional diagram

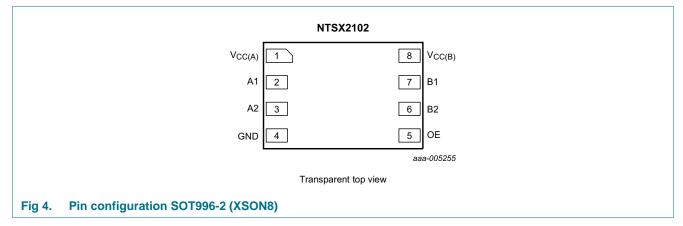


Dual supply translating transceiver; open drain; auto direction sensing

# 7. Pinning information

#### 7.1 Pinning





# 7.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
B2, B1	6, 7	data input or output (referenced to $V_{\text{CC}(B)}$ )
GND	4	ground (0 V)
V <sub>CC(A)</sub>	1	supply voltage A
A2, A1	3, 2	data input or output (referenced to $V_{\text{CC}(A)}$ )
OE	5	output enable input (active HIGH; referenced to $V_{\text{CC(A)}}$ )
V <sub>CC(B)</sub>	8	supply voltage B

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# 8. Functional description

Table 4. Function table[1]

Supply voltage		Input	Input/output		
$V_{CC(A)}$ $V_{CC(B)}$		OE	An	Bn	
1.65 V to 5.5 V 1.65 V to 5.5 V		L	Z	Z	
1.65 V to 5.5 V	1.65 V to 5.5 V	Н	input or output	output or input	
GND[2]	GND[2]	Χ	Z	Z	

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

# 9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

		<b>0</b> , (	,	10	,
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		-0.5	+6.5	V
$V_{CC(B)}$	supply voltage B		-0.5	+6.5	V
VI	input voltage	A port and OE input	<u>[1][2]</u> –0.5	+6.5	V
		B port	[1][2] -0.5	+6.5	V
Vo	output voltage	Active mode	<u>[1][2]</u>		
		A or B port	-0.5	$V_{CCO} + 0.5$	V
		Power-down or 3-state mode	<u>[1]</u>		
		A or B port	-0.5	+6.5	V mA
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	<b>–50</b>	-	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	<b>–50</b>	-	mA
Io	output current	$V_O = 0 V \text{ to } V_{CCO}$	[2] _	±50	mA
I <sub>CC</sub>	supply current	I <sub>CC(A)</sub> or I <sub>CC(B)</sub>	-	100	mA
I <sub>GND</sub>	ground current		-100	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +85  ^{\circ}\text{C}$	-	250	mW

<sup>[1]</sup> The minimum input and minimum output voltage ratings may be exceeded if the input and output current ratings are observed.

# 10. Recommended operating conditions

Table 6. Recommended operating conditions[1]

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		1.65	5.5	V
V <sub>CC(B)</sub>	supply voltage B		1.65	5.5	V

<sup>[2]</sup> When either  $V_{CC(A)}$  or  $V_{CC(B)}$  is at GND level, the device goes into power-down mode.

<sup>[2]</sup>  $V_{\text{CCO}}$  is the supply voltage associated with the output.

#### Dual supply translating transceiver; open drain; auto direction sensing

Table 6. Recommended operating conditions [1] ... continued

Symbol	Parameter	Conditions	Min	Max	Unit
T <sub>amb</sub>	ambient temperature		-40	+85	°C
Δt/ΔV	input transition rise and fall rate	A, B or OE port			
		$V_{CC(A)} = 1.65 \text{ V to } 5.5 \text{ V};$ $V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$	-	10	ns/V

<sup>[1]</sup> Hold the A and B sides of an unused I/O pair in the same state, both at  $V_{\text{CCI}}$  or both at GND.

## 11. Static characteristics

#### Table 7. Typical static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); T<sub>amb</sub> = 25 °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C <sub>I</sub>	input capacitance	OE input; $V_{CC(A)} = V_{CC(B)} = 0 \text{ V}$	-	2.2	-	pF
C <sub>I/O</sub>	input/output capacitance	A or B port; $V_{CC(A)} = 5.0 \text{ V}$ ; $V_{CC(B)} = 5.0 \text{ V}$	-	10	-	pF

<sup>[1]</sup>  $V_{CCO}$  is the supply voltage associated with the output.

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

	Parameter	Parameter Conditions				Unit
				Min	Max	
$V_{IH}$	HIGH-level input	A or B port			'	'
	voltage	$V_{CC(A)} = 1.65 \text{ V to } 5.5 \text{ V}; V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$	[1]	$V_{CCI}-0.4$	-	V
		OE input				
		$V_{CC(A)} = 1.65 \text{ V}$ to 5.5 V; $V_{CC(B)} = 1.65 \text{ V}$ to 5.5 V		0.65V <sub>CC(A)</sub>	-	V
V <sub>IL</sub> LOW-level input voltage	•	A or B port				
	$V_{CC(A)} = 1.65 \text{ V to } 5.5 \text{ V}; V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$		-	0.4	V	
		OE input				
		$V_{CC(A)} = 1.65 \text{ V to } 5.5 \text{ V}; V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$		-	0.35V <sub>CC(A)</sub>	V
V <sub>OL</sub>	LOW-level output	A or B port; $I_O = 6 \text{ mA}$	[2]			
	voltage	$V_{I} \le 0.15 \text{ V}; \ V_{CC(A)} = 1.65 \text{ V to } 5.5 \text{ V}; \ V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$		-	0.4	V
II	input leakage current	OE input; $V_I$ = 0 V to $V_{CC(A)}$ ; $V_{CC(A)}$ = 1.65 V to 5.5 V; $V_{CC(B)}$ = 1.65 V to 5.5 V		-	±1	μА
I <sub>OZ</sub>	OFF-state output current	A or B port; $V_O = 0$ V or $V_{CCO}$ ; $V_{CC(A)} = 0$ V to 5.5 V; $V_{CC(B)} = 0$ V to 5.5 V	[2]	-	±2	μА
I <sub>OFF</sub>	power-off leakage current	A port; $V_1$ or $V_0 = 0$ V to 5.5 V; $V_{CC(A)} = 0$ V; $V_{CC(B)} = 0$ V to 5.5 V		-	±2	μА
		B port; $V_I$ or $V_O = 0$ V to 5.5 V; $V_{CC(B)} = 0$ V; $V_{CC(A)} = 0$ V to 5.5 V		-	±2	μΑ

#### Dual supply translating transceiver; open drain; auto direction sensing

 Table 8.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		–40 °C t	5 to +85 °C Max  5 2 -2	Unit
				Min	Max	
$I_{CC}$	supply current	$V_I = 0 \text{ V or } V_{CCI}; I_O = 0 \text{ A}$	[1]			
		I <sub>CC(A)</sub>				
		$V_{CC(A)}$ = 1.65 V to 5.5 V; $V_{CC(B)}$ = 1.65 V to 5.5 V; OE = LOW or HIGH		-	5	μА
		$V_{CC(A)} = 1.65 \text{ V to } 5.5 \text{ V}; V_{CC(B)} = 0 \text{ V}$		-	2	μΑ
		$V_{CC(A)} = 0 \text{ V}; V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$		-	-2	μΑ
		I <sub>CC(B)</sub>				
		$V_{CC(A)}$ = 1.65 V to 5.5 V; $V_{CC(B)}$ = 1.65 V to 5.5 V; OE = LOW		-	5	μА
		$V_{CC(A)} = 1.65 \text{ V to } 5.5 \text{ V}; V_{CC(B)} = 0 \text{ V}$		-	-2	μΑ
		$V_{CC(A)} = 0 \text{ V}; V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$		-	2	μΑ

<sup>[1]</sup> V<sub>CCI</sub> is the supply voltage associated with the input.

# 12. Dynamic characteristics

#### Table 9. Typical dynamic characteristics for temperature 25 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 7</u>; for waveforms see <u>Figure 5</u> and <u>Figure 6</u>.

•		77							
Symbol	Symbol Parameter Conditions			V <sub>CCO</sub> [1]					
			1.8 V	2.5 V	3.3 V	5.0 V			
t <sub>TLH</sub>	LOW to HIGH output transition time	A or B port	7	5	4	3	ns		
t <sub>THL</sub>	HIGH to LOW output transition time	A or B port	4	6	8	11	ns		
$C_{PD}$	power dissipation capacitance	$OE = V_{CC(A)}; V_{CC(A)} = V_{CC(B)};$ $f_I = 400 \text{ kHz}; V_I = V_{CCI}^{3}$	[2] -	-	-	13.5	pF		

<sup>[1]</sup>  $V_{CCO}$  is the supply voltage associated with the output.

[2]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

[3]  $V_{CCI}$  is the supply voltage associated with the input.

<sup>[2]</sup>  $V_{CCO}$  is the supply voltage associated with the output.

## Dual supply translating transceiver; open drain; auto direction sensing

Table 10. Dynamic characteristics for temperature range –40 °C to +85 °C[1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7; for wave forms see Figure 5 and Figure 6.

Symbol	Parameter	Conditions		V <sub>CC(B)</sub>								Unit
				1.8 V ± 0.15 V		2.5 V ±	Ŀ 0.2 V	3.3 V =	Ŀ 0.3 V	5.0 V	± 0.5 V	
				Тур	Max	Тур	Max	Тур	Max	Тур	Max	
V <sub>CC(A)</sub> =	1.8 V ± 0.15 V											
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B		3	7	3	6	3	5	5	7	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B		5	12	5	8	4	8	4	7	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A		3	7	3	6	3	5	5	7	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A		5	12	1	3	1	2	1	2	ns
$t_{PZL}$	OFF-state to LOW	OE to A		9	16	9	18	10	14	10	15	ns
	propagation delay	OE to B		9	16	6	12	6	12	6	14	ns
t <sub>PLZ</sub>	LOW to OFF-state	OE to A		100	120	100	120	100	120	100	120	ns
	propagation delay	OE to B		100	120	100	120	100	120	100	120	ns
t <sub>sk(o)</sub>	output skew time	between channels	[2]	-	1	-	1	-	1	-	1	ns
f <sub>data</sub>	data rate			-	18	-	18	-	18	-	18	Mbps
V <sub>CC(A)</sub> =	2.5 V ± 0.2 V											
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B		3	6	2	5	2	5	2	5	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B		1	3	2	4	2.5	7	2.5	5	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A		3	6	2	5	2	5	2	5	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A		5	8	2	4	1.5	3	1	3	ns
$t_{PZL}$	OFF-state to LOW	OE to A		6	12	5	10	8	10	5	8	ns
	propagation delay	OE to B		9	18	5	10	4.5	9	4	8	ns
t <sub>PLZ</sub>	LOW to OFF-state	OE to A		100	120	100	120	100	120	100	120	ns
	propagation delay	OE to B		100	120	100	120	100	120	100	120	ns
t <sub>sk(o)</sub>	output skew time	between channels	[2]	-	1	-	1	-	1	-	1	ns
f <sub>data</sub>	data rate			-	18	-	32	-	32	-	32	Mbps
	3.3 V ± 0.3 V											
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B		3	5	2	5	2	4	2	4	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B		1	2	1.5	3	1.5	3	2	4	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A		3	5	2	5	2	4	2	4	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A		4	8	2.5	7	1.5	3	1	3	ns
t <sub>PZL</sub>	OFF-state to LOW propagation delay	OE to A OE to B		6 10	12 14	4.5 5	9 10	6 6	9	4	7 8	ns ns

NTSX2102

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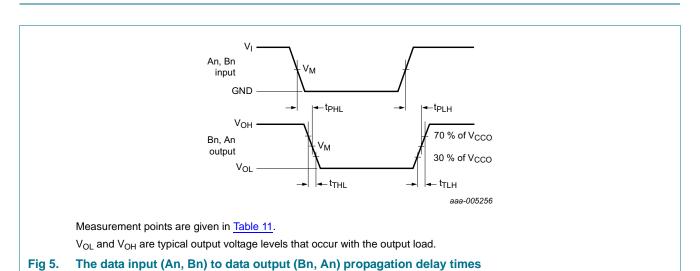
#### Dual supply translating transceiver; open drain; auto direction sensing

Table 10. Dynamic characteristics for temperature range -40 °C to +85 °C[1] Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 7</u>; for wave forms see <u>Figure 5</u> and <u>Figure 6</u>.

Symbol	Parameter	Conditions		V <sub>CC(B)</sub>								Unit	
				1.8 V ±	0.15 V	2.5 V ±	0.2 V	3.3 V ±	0.3 V	5.0 V ±	0.5 V		
				Тур	Max	Тур	Max	Тур	Max	Тур	Max		
$t_{PLZ}$	LOW to OFF-state	OE to A		100	120	100	120	100	120	100	120	ns	
	propagation delay	OE to B		100	120	100	120	100	120	100	120	ns	
t <sub>sk(o)</sub>	output skew time	between channels	[2]	-	1	-	1	-	1	-	1	ns	
f <sub>data</sub>	data rate			-	18	-	32	-	40	-	40	Mbps	
V <sub>CC(A)</sub> =	5.0 V ± 0.5 V												
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B		5	7	2	5	2	4	2	4	ns	
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B		1	2	1	3	1	3	1	3	ns	
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A		5	7	2	5	2	4	2	4	ns	
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A		4	7	2.5	5	2	4	1	3	ns	
t <sub>PZL</sub>	OFF-state to LOW	OE to A		6	14	4	8	4	8	3	5	ns	
	propagation delay	OE to B		10	15	5	8	4	7	4	5	ns	
t <sub>PLZ</sub>	LOW to OFF-state	OE to A		100	120	100	120	100	120	100	120	ns	
	propagation delay	OE to B		100	120	100	120	100	120	100	120	ns	
t <sub>sk(o)</sub>	output skew time	between channels	[2]	-	1	-	1	-	1	-	1	ns	
f <sub>data</sub>	data rate			-	18	-	32	-	40	-	52	Mbps	

<sup>[1]</sup> All typical values are measured at nominal  $V_{CC}$  and  $T_{amb}$  = 25 °C.

#### 13. Waveforms



<sup>[2]</sup> Skew between any two outputs of the same package switching in the same direction.

#### Dual supply translating transceiver; open drain; auto direction sensing

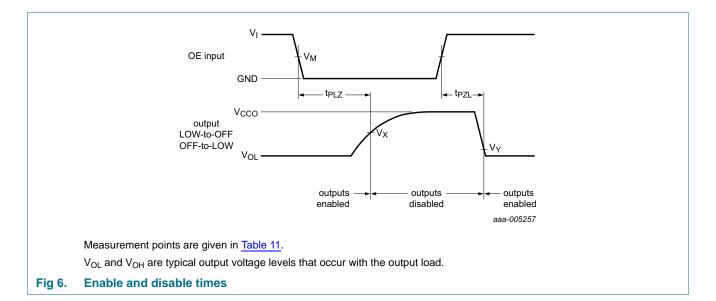


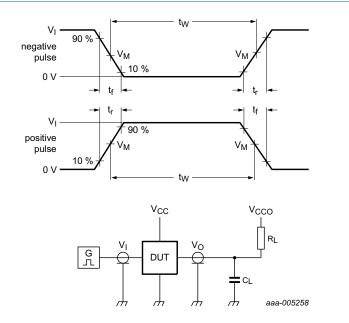
Table 11. Measurement points[1][2]

Supply voltage	Input	Output			
V <sub>CCO</sub>	V <sub>M</sub>	V <sub>M</sub>	$V_X$	V <sub>Y</sub>	
1.65 V to 5.5 V	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	0.5V <sub>CCO</sub>	0.1V <sub>CCO</sub>	

<sup>[1]</sup>  $V_{CCI}$  is the supply voltage associated with the input.

<sup>[2]</sup>  $V_{CCO}$  is the supply voltage associated with the output.

#### Dual supply translating transceiver; open drain; auto direction sensing



Test data is given in Table 12.

All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz;  $Z_O$  = 50  $\Omega$ ;  $dV/dt \geq$  1.0 V/ns.

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $V_{CC0}$  = Supply voltage associated with the output.

Fig 7. Test circuit for measuring switching times

Table 12. Test data

Supply voltage				Load	Load	
V <sub>CC(A)</sub>	V <sub>CC(B)</sub>	V <sub>I</sub> [1]	t <sub>r</sub> /t <sub>f</sub>	CL	R <sub>L</sub>	
1.65 V to 1.95 V	1.65 V to 1.95 V	$V_{CCI}$	≤ 2.0 ns	50 pF	$2.2~\mathrm{k}\Omega$	
2.3 V to 2.7 V	2.3 V to 2.7 V	$V_{CCI}$	≤ 2.0 ns	50 pF	2.2 kΩ	
3.0 V to 3.6 V	3.0 V to 3.6 V	$V_{CCI}$	≤ 2.5 ns	50 pF	2.2 kΩ	
4.5 V to 5.5 V	4.5 V to 5.5 V	$V_{CCI}$	≤ 2.5 ns	50 pF	2.2 kΩ	

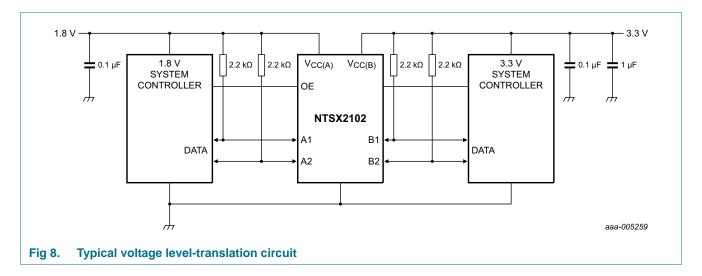
<sup>[1]</sup>  $V_{CCI}$  is the supply voltage associated with the input.

Dual supply translating transceiver; open drain; auto direction sensing

# 14. Application information

#### 14.1 Applications

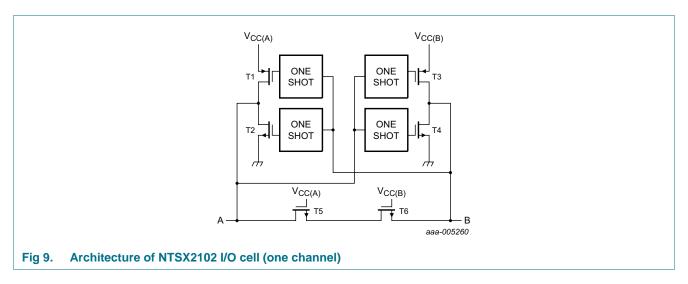
The NTSX2102 can be used in point-to-point applications to interface between devices or systems operating at different supply voltages. The device is targeted at I<sup>2</sup>C or 1-wire buses which use open-drain drivers.



## 14.2 Architecture

The architecture of the NTSX2102 is shown in Figure 9. The device does not require an extra input signal to control the direction of data flow from A to B or B to A. The NTSX2102 is a "switch" type voltage translator, it employs two key circuits to enable voltage translation:

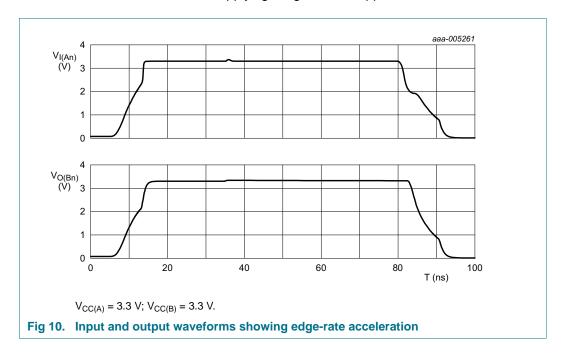
- 1. Two pass-gate transistors (N-channel) that tie the ports together.
- 2. An output edge-rate accelerator that detects and accelerates rising and falling edges on the I/O pins (see <u>Figure 10</u>).

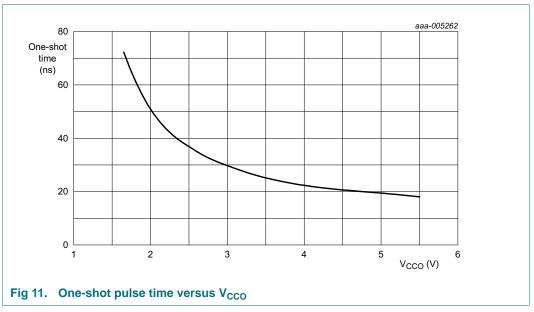


NTSX2102

#### Dual supply translating transceiver; open drain; auto direction sensing

During an input transition, a one-shot accelerates the output transition by switching on the PMOS transistors (T1, T3) for a LOW-to-HIGH transition. Alternatively, it switches on the NMOS transistors (T2, T4) for a HIGH-to-LOW transition. Once activated, the one-shot is de-activated after approximately 25 ns (see Figure 11). During the acceleration time, the driver output resistance is between approximately 10  $\Omega$  and 35  $\Omega$ . To avoid signal contention, the application must not exceed the maximum data rate or wait for the one-shot circuit to turn-off, before applying a signal in the opposite direction.





#### Dual supply translating transceiver; open drain; auto direction sensing

#### 14.3 Input driver requirements

As the NTSX2102 is a switch type translator, properties of the input driver directly affect the output signal. The external open-drain driver applied to an I/O, determines the static current sinking capability of the system. The maximum data rate, output transition times  $(t_{THL},\,t_{TLH})$  and propagation delays  $(t_{PHL},\,t_{PLH})$  are dependent upon the output impedance and edge-rate of the external driver.

#### 14.4 Output load considerations

The maximum lumped capacitive load that can be driven is dependent upon the one-shot pulse duration and has been tuned to 600 pF. In cases with higher capacitive loading, there is a risk that the output does not reach the positive rail within the one-shot pulse duration. To avoid excessive capacitive loading and to ensure correct triggering of the one-shot, use short trace lengths and low capacitance connectors on NTSX2102 PCB layouts. The length of the PCB trace should be such that the round-trip delay of any reflection is within the one-shot pulse duration. Such a length ensures low impedance termination and avoids output signal oscillations and one-shot retriggering.

#### 14.5 Output enable (OE)

An output enable input (OE) is used to disable the device. Setting OE = LOW causes all I/Os to assume the high-impedance OFF-state.

#### 14.6 Power-up

When either of the supplies  $V_{CC(n)}$  is at 0 V, outputs are in the high-impedance OFF-state. One of the advantages of NTSX translators is that either  $V_{CC(A)}$  or  $V_{CC(B)}$  may be powered up first. To reduce dissipation during power-up, ensure that output enable (OE) is defined. Connect it via a pull down resistor to GND or, if the application allows, hardwired to  $V_{CC(A)}$ . If the OE pin is hardwired to  $V_{CC(A)}$ , either supply can be powered up or down first. If a pull down is used, the following sequences are recommended.

#### For power-up:

- 1. Apply power to either supply pin
- 2. Apply power to other supply pin
- 3. Enable the device by driving OE HIGH

#### For power down:

- 1. Disable the device by driving OE LOW
- 2. Remove power from either supply pin
- 3. Remove power from other supply pin

#### 14.7 Pull-up resistors on I/O lines

Each A port I/O requires a pull-up resistor to  $V_{CC(A)}$ , and each B port I/O requires a pull-up resistor to  $V_{CC(B)}$ . Choose the magnitude of the pull-up resistors to ensure that the output voltage levels meet the application requirement.

#### Dual supply translating transceiver; open drain; auto direction sensing

# 15. Package outline

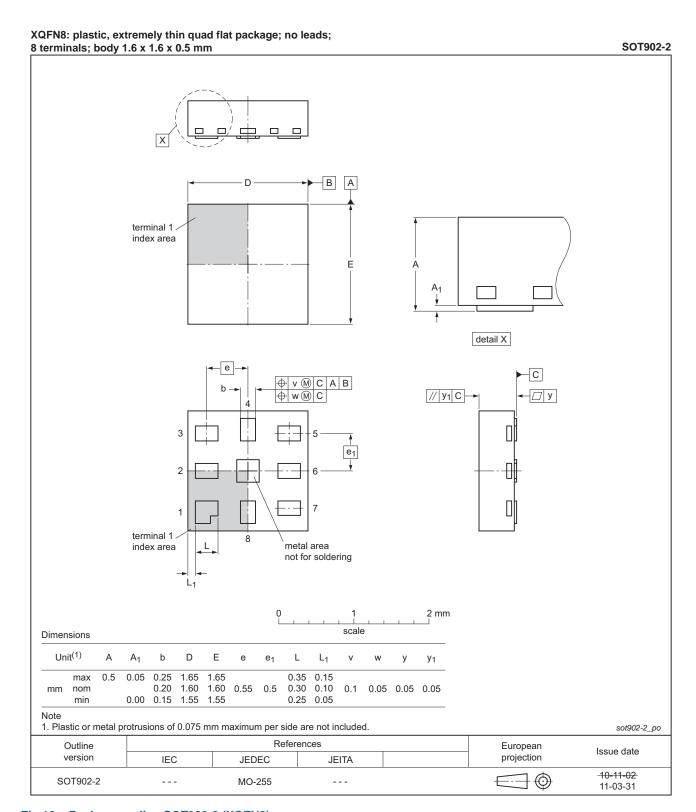


Fig 12. Package outline SOT902-2 (XQFN8)

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#### Dual supply translating transceiver; open drain; auto direction sensing

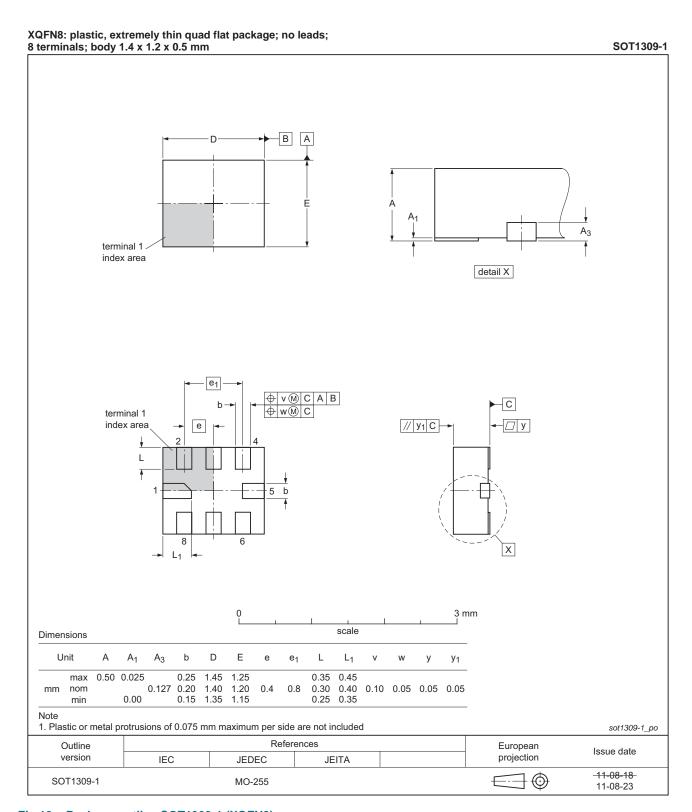


Fig 13. Package outline SOT1309-1 (XQFN8)

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#### Dual supply translating transceiver; open drain; auto direction sensing

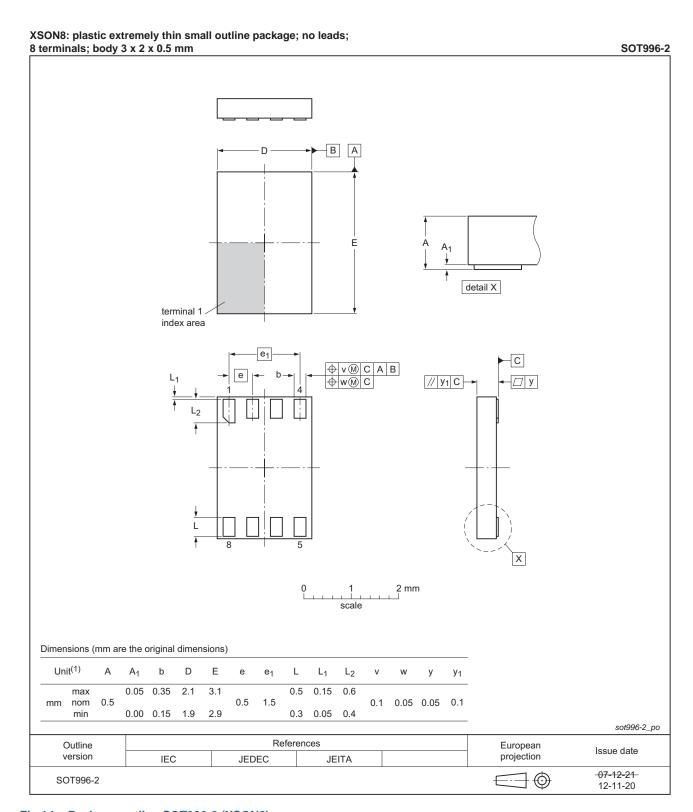


Fig 14. Package outline SOT996-2 (XSON8)

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## Dual supply translating transceiver; open drain; auto direction sensing

# 16. Abbreviations

#### Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
GPIO	General Purpose Input Output
HBM	Human Body Model
I <sup>2</sup> C	Inter-Integrated Circuit
PCB	Printed Circuit Board
PMOS	Positive Metal Oxide Semiconductor
SMBus	System Management Bus
UART	Universal Asynchronous Receiver Transmitter
UTLP	Ultra Thin Leadless Package

# 17. Revision history

#### Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
NTSX2102 v.2	20130211	Product data sheet	-	NTSX2102 v.1.1			
Modifications:	s: • For type number NTSX2102GD XSON8U has changed to XSON8.						
NTSX2102 v.1.1	20121121	Product data sheet	-	NTSX2102 v.1			
Modifications:	Section 1 "General description" text updated.						
NTSX2102 v.1	20121119	Product data sheet	-	-			

#### Dual supply translating transceiver; open drain; auto direction sensing

# 18. Legal information

#### 18.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [2] The term 'short data sheet' is explained in section "Definitions"
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NTSX2102

#### Dual supply translating transceiver; open drain; auto direction sensing

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#### Dual supply translating transceiver; open drain; auto direction sensing

# 20. Contents

1	General description
2	Features and benefits
3	Applications
4	Ordering information
5	Marking 2
6	Functional diagram 2
7	Pinning information
7.1	Pinning
7.2	Pin description
8	Functional description 4
9	Limiting values 4
10	Recommended operating conditions 4
11	Static characteristics 5
12	Dynamic characteristics 6
13	Waveforms
14	Application information
14.1	Applications
14.2	Architecture 11
14.3	Input driver requirements
14.4	Output load considerations
14.5	Output enable (OE)
14.6	Power-up
14.7	Pull-up resistors on I/O lines
15	Package outline
16	Abbreviations
17	Revision history 17
18	Legal information 18
18.1	Data sheet status
18.2	Definitions
18.3	Disclaimers
18.4	Trademarks
19	Contact information
20	Contents

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